

1. General description

Ultrafast, epitaxial rectifier diode in a SOD113 (TO-220F) plastic package.

2. Features and benefits

- Fast switching
- Low thermal resistance
- Soft recovery characteristic
- Isolated package
- Low forward voltage drop
- High thermal cycling performance

3. Applications

- Output rectifiers in high frequency switched-mode power supplies
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

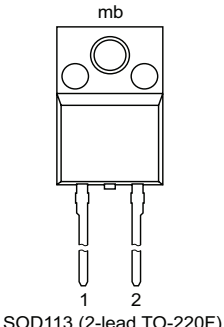
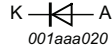
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit
Absolute maximum rating						
V_{RRM}	repetitive peak reverse voltage		600			V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; square-wave pulse; $T_h \leq 85$ °C; Fig. 1 ; Fig. 2 ; Fig. 3	9			A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25$ μ s; $T_h \leq 85$ °C; square-wave pulse	18			A
I_{FSM}	non-repetitive peak forward current	$t_p = 10$ ms; $T_{j(init)} = 25$ °C; sine-wave pulse; Fig. 4	91			A
		$t_p = 8.3$ ms; $T_{j(init)} = 25$ °C; sine-wave pulse	100			A
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V_F	forward voltage	$I_F = 8$ A; $T_j = 25$ °C; Fig. 6	-	1.12	1.26	V
		$I_F = 8$ A; $T_j = 125$ °C	-	1.03	-	V
		$I_F = 8$ A; $T_j = 150$ °C; Fig. 6	-	0.97	1.11	V
Dynamic characteristics						
t_{rr}	reverse recovery time	$I_F = 1$ A; $V_R = 30$ V; $di_F/dt = 100$ A/ μ s; $T_j = 25$ °C; Fig. 7	-	32	60	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	 <p>SOD113 (2-lead TO-220F)</p>	
2	A	anode		
mb	mb	mounting base; isolated		

6. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BYV29X-600	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 'full pack'	SOD113

7. Marking

Table 4. Marking codes

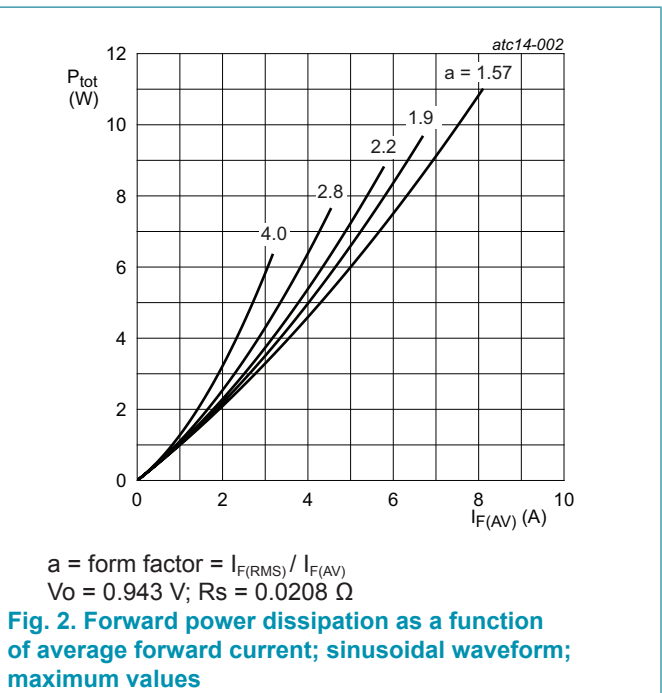
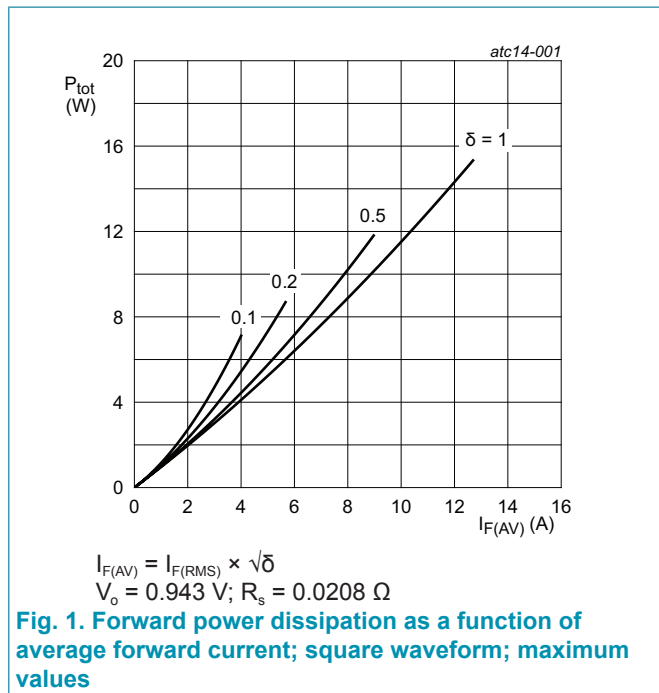
Type number	Marking codes
BYV29X-600	BYV29X-600

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
V_{RWM}	crest working reverse voltage		600	V
V_R	reverse voltage	DC	600	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$; square-wave pulse; $T_h \leq 85$ °C; Fig. 1 ; Fig. 2 ; Fig. 3	9	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25$ μ s; $T_h \leq 85$ °C; square-wave pulse	18	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10$ ms; $T_{j(init)} = 25$ °C; sine-wave pulse; Fig. 4	91	A
		$t_p = 8.3$ ms; $T_{j(init)} = 25$ °C; sine-wave pulse	100	A
T_{stg}	storage temperature		-40 to 150	°C
T_j	junction temperature		150	°C



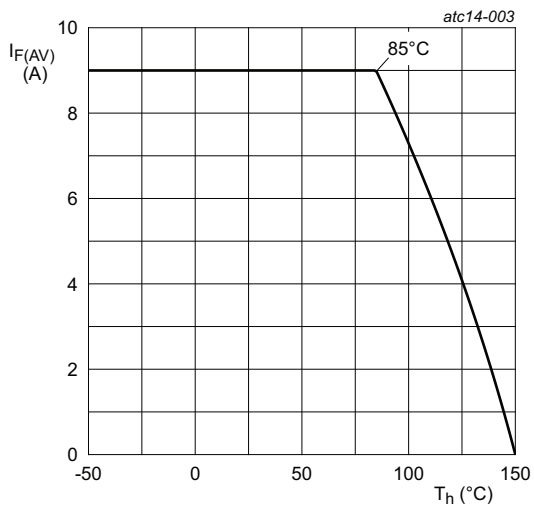


Fig. 3. Forward current as a function of heatsink temperature; maximum values

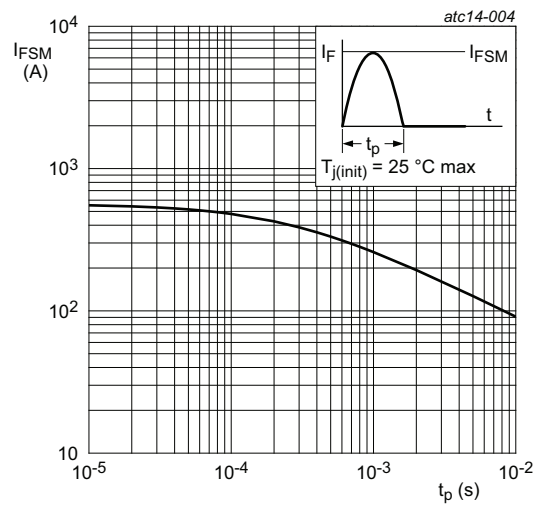


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	with heatsink compound; Fig. 5	-	-	5.5	K/W
		without heatsink compound	-	-	5.9	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W

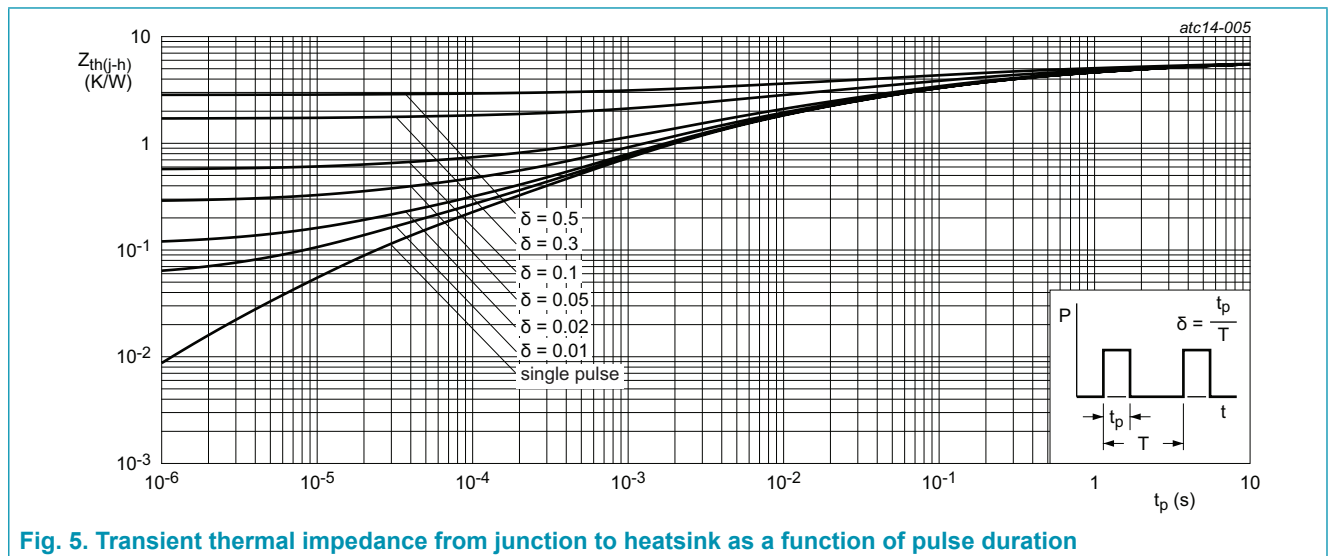


Fig. 5. Transient thermal impedance from junction to heatsink as a function of pulse duration

10. Isolation characteristics

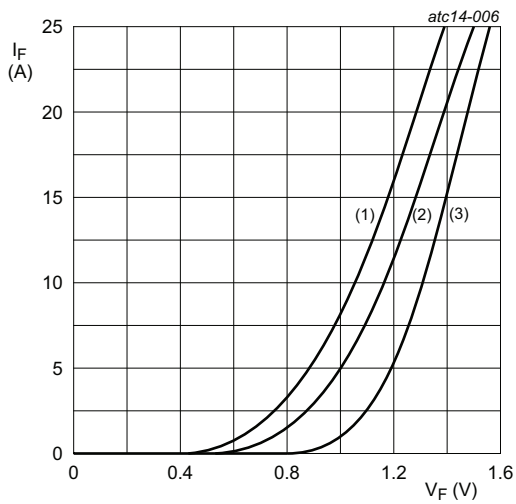
Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	50 Hz \leq f \leq 60 Hz; RH \leq 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C_{isol}	isolation capacitance	from cathode to external heatsink	-	10	-	PF

11. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V_F	forward current	$I_F = 8\text{ A}; T_j = 25\text{ °C}; \text{Fig. 6}$	-	1.12	1.26	V
		$I_F = 8\text{ A}; T_j = 125\text{ °C}$	-	1.03	-	V
		$I_F = 8\text{ A}; T_j = 150\text{ °C}; \text{Fig. 6}$	-	0.97	1.11	V
I_R	reverse current	$V_R = 600\text{ V}; T_j = 25\text{ °C}$	-	2	50	μA
		$V_R = 600\text{ V}; T_j = 100\text{ °C}$	-	0.3	-	mA
		$V_R = 600\text{ V}; T_j = 125\text{ °C}$	-	-	3	mA
Dynamic characteristics						
Q_f	reverse charge	$I_F = 1\text{ A}; V_R = 30\text{ V}; dI_F/dt = 100\text{ A}/\mu\text{s}; T_j = 25\text{ °C}; \text{Fig. 7}$	-	37	-	nC
t_{rr}	reverse recovery time		-	32	60	ns
I_{RM}	peak reverse recovery current		-	2.3	-	A
dI_{rr}/dt	peak rate of fall of reverse recovery current		-	297	-	$\text{A}/\mu\text{s}$
Q_f	reverse charge	$I_F = 8\text{ A}; V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 25\text{ °C}; \text{Fig. 7}$	-	220	-	nC
t_{rr}	reverse recovery time		-	43	-	ns
I_{RM}	peak reverse recovery current		-	10	-	A
dI_{rr}/dt	peak rate of fall of reverse recovery current		-	655	-	$\text{A}/\mu\text{s}$
Q_f	reverse charge	$I_F = 8\text{ A}; V_R = 400\text{ V}; dI_F/dt = 200\text{ A}/\mu\text{s}; T_j = 25\text{ °C}; \text{Fig. 7}$	-	165	-	nC
t_{rr}	reverse recovery time		-	59	-	ns
I_{RM}	peak reverse recovery current		-	5.6	-	A
dI_{rr}/dt	peak rate of fall of reverse recovery current		-	215	-	$\text{A}/\mu\text{s}$
Q_f	reverse charge	$I_F = 8\text{ A}; V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 125\text{ °C}; \text{Fig. 7}$	-	425	-	nC
t_{rr}	reverse recovery time		-	57	-	ns
I_{RM}	peak reverse recovery current		-	15	-	A
dI_{rr}/dt	peak rate of fall of reverse recovery current		-	1661	-	$\text{A}/\mu\text{s}$
Q_f	reverse charge	$I_F = 8\text{ A}; V_R = 400\text{ V}; dI_F/dt = 200\text{ A}/\mu\text{s}; T_j = 125\text{ °C}; \text{Fig. 7}$	-	315	-	nC
t_{rr}	reverse recovery time		-	70	-	ns
I_{RM}	peak reverse recovery current		-	9	-	A
dI_{rr}/dt	peak rate of fall of reverse recovery current		-	1181	-	$\text{A}/\mu\text{s}$



$V_o = 0.943 \text{ V}; R_s = 0.0208 \Omega$
 (1) $T_j = 150 \text{ }^\circ\text{C}$; typical values
 (2) $T_j = 150 \text{ }^\circ\text{C}$; maximum values
 (3) $T_j = 25 \text{ }^\circ\text{C}$; maximum values

Fig. 6. Forward current as a function of forward voltage

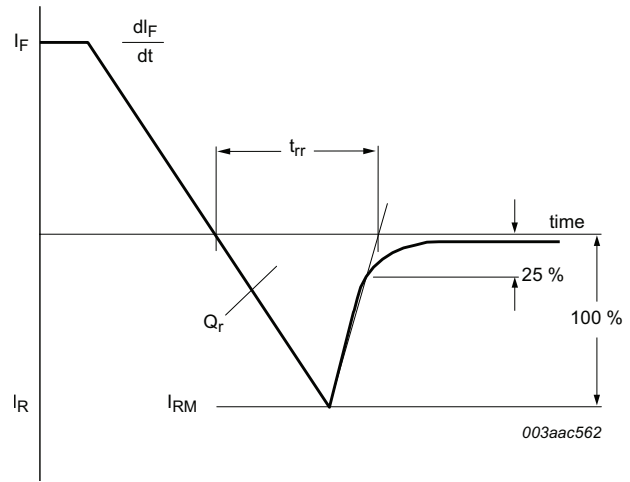
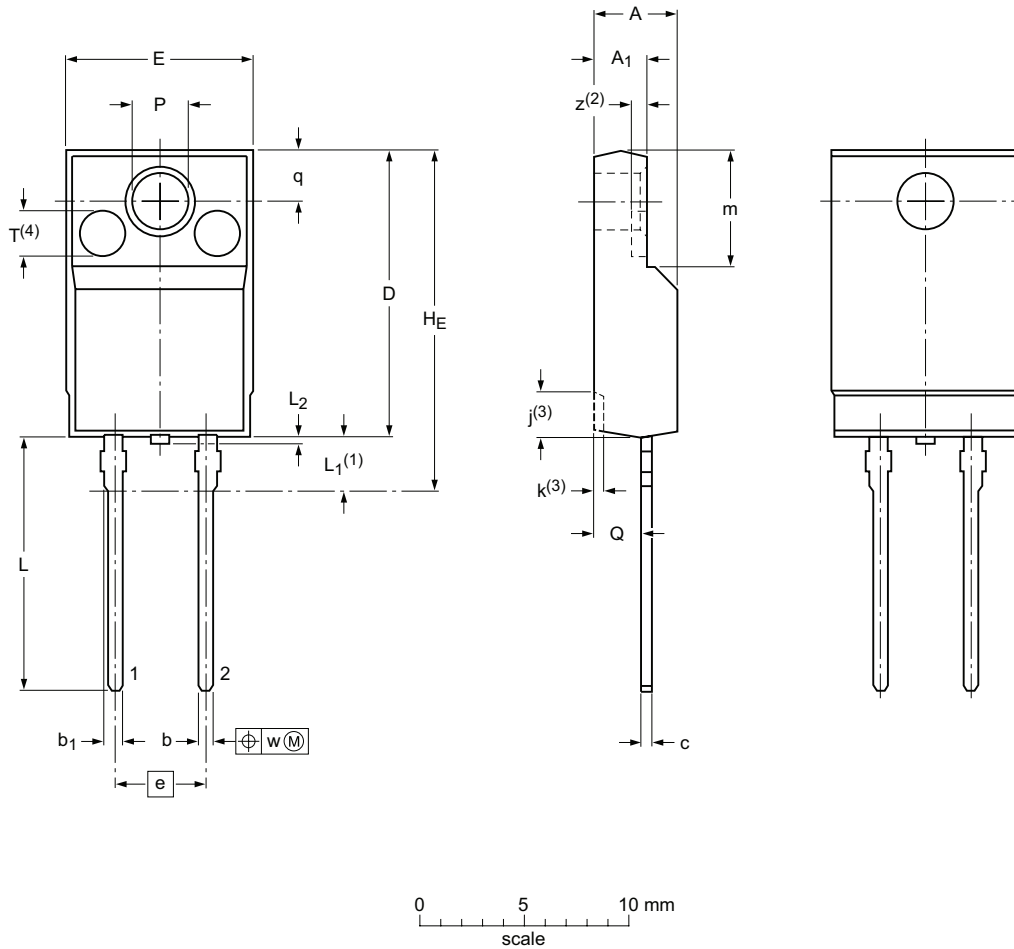


Fig. 7. Reverse recovery definitions; ramp recovery

12. Package outline

Plastic single-ended package; isolated heatsink mounted;
1 mounting hole; 2-lead TO-220 `full pack`

SOD113



Dimensions (mm are the original dimensions)

Unit	A	A ₁	b	b ₁	c	D	E	e	H _E max	j ⁽³⁾	k ⁽³⁾	L	L ₁ ⁽¹⁾	L ₂ max	m	P	Q	q	T ⁽⁴⁾	w	z ⁽²⁾	
max	4.6	2.9	0.9	1.1	0.7	15.8	10.3		19.0	2.7	0.6	14.4	3.3	0.5	6.5	3.2	2.6					
nom								5.08											2.6	2.55	0.4	0.8
min	4.0	2.5	0.7	0.9	0.4	15.2	9.7			1.7	0.4	13.5	2.8		6.3	3.0	2.3					

Notes

1. Terminals are uncontrolled within zone L1.
2. z is depth of T.
3. Dot lines area designs may vary.
4. Eject pin mark is for reference only.

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Outline version	References			European projection	Issue date
	IEC	JEDEC	JEITA		
SOD113	2-lead TO-220F				07-06-08 15-08-28

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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